

# **BAP65-05W**

## Silicon PIN diode

Rev. 2 — 27 September 2010

Product data sheet

### 1. Product profile

### 1.1 General description

Two planar PIN diodes in a SOT323 small SMD plastic package.

### 1.2 Features and benefits

- Two elements in common cathode configuration
- High voltage, current controlled
- RF resistor for RF switches
- Low diode capacitance
- Low diode forward resistance (low loss)

### 1.3 Applications

- RF attenuators and switches
- Bandswitch for TV tuners
- Series diode for mobile communication transmit/receive switch

## 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	anode (a <sub>1</sub> )		•
2	anode (a <sub>2</sub> )	3	3
3	common cathode	1 2	1 2 sym136

## 3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BAP65-05W	-	plastic surface-mounted package; 3 leads	SOT323		



## 4. Marking

Table 3. Marking codes

Type number	Marking code
BAP65-05W	V6-

## 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	continuous reverse voltage		-	30	V
I <sub>F</sub>	continuous forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> ≤ 90 °C	-	240	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C

### 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th j-s</sub>	thermal resistance from junction to soldering point		250	K/W

### 7. Characteristics

Table 6. Characteristics

 $T_j = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 50 \text{ mA}$	-	0.9	1.1	V
I <sub>R</sub>	reverse leakage current	V <sub>R</sub> = 20 V	-	-	20	nA
C <sub>d</sub>	diode capacitance	$V_R = 0 V$ ; $f = 1 MHz$	-	0.7	-	pF
		V <sub>R</sub> = 1 V; f = 1 MHz	-	0.575	0.9	pF
		$V_R = 3 \text{ V}; f = 1 \text{ MHz}$	-	- 0.525	8.0	pF
		$V_R = 20 \text{ V}; f = 1 \text{ MHz}$	-	0.425	-	pF
$r_D$	diode forward resistance	$I_F = 1 \text{ mA}; f = 100 \text{ MHz}$	-	1	-	Ω
		$I_F = 5 \text{ mA}; f = 100 \text{ MHz}$	<u>[1]</u> -	0.65	0.95	Ω
		I <sub>F</sub> = 10 mA; f = 100 MHz	<u>[1]</u> -	0.56	0.9	Ω
		I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.35	-	Ω
$ s_{21} ^2$	isolation	$V_R = 0$ ; $f = 900 \text{ MHz}$	-	9.3	-	dB
		V <sub>R</sub> = 0; f = 1800 MHz	-	5.3	-	dB
		V <sub>R</sub> = 0; f = 2450 MHz	-	3.5	-	dB

BAP65-05W

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**Table 6.** Characteristics ...continued  $T_i = 25$  °C unless otherwise specified.

,						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
S <sub>21</sub>   <sup>2</sup> ii	insertion loss	$I_F = 1 \text{ mA}; f = 900 \text{ MHz}$	-	0.11	-	dB
		I <sub>F</sub> = 1 mA; f = 1800 MHz	-	0.17	-	dB
		I <sub>F</sub> = 1 mA; f = 2450 MHz	-	0.24	-	dB
$ s_{21} ^2$	insertion loss	$I_F = 5 \text{ mA}; f = 900 \text{ MHz}$	-	0.08	-	dB
		$I_F = 5 \text{ mA}$ ; $f = 1800 \text{ MHz}$	-	0.14	-	dB
		$I_F = 5 \text{ mA}$ ; $f = 2450 \text{ MHz}$	-	0.21	-	dB
$ s_{21} ^2$	insertion loss	$I_F = 10 \text{ mA}; f = 900 \text{ MHz}$	-	0.08	-	dB
		$I_F = 10 \text{ mA}; f = 1800 \text{ MHz}$	-	0.14	-	dB
		$I_F = 10 \text{ mA}; f = 2450 \text{ MHz}$	-	0.21	-	dB
$ s_{21} ^2$	insertion loss	$I_F = 100 \text{ mA}; f = 900 \text{ MHz}$	-	0.06	-	dB
		$I_F = 100 \text{ mA}; f = 1800 \text{ MHz}$	-	0.13	-	dB
		I <sub>F</sub> = 100 mA; f = 2450 MHz	-	0.2	-	dB
<b>τ</b> լ	charge carrier life time	when switched from $I_F$ = 10 mA to $I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA	-	0.17	-	μS
L <sub>S</sub>	series inductance	$I_F = 100 \text{ mA}; f = 100 \text{ MHz}$	-	1.4	-	nΗ

<sup>[1]</sup> Guaranteed on AQL basis: inspection level S4, AQL 1.0.

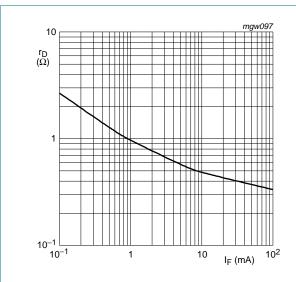
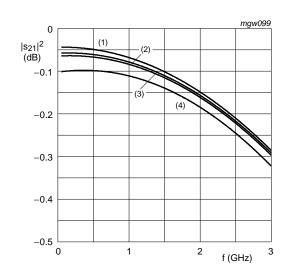


Fig 1. Forward resistance as a function of forward current; typical values

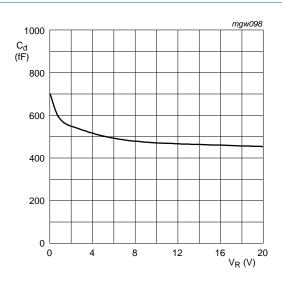
 $f = 100 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}$ 



- (1)  $I_F = 100 \text{ mA}$
- (2)  $I_F = 10 \text{ mA}$
- (3)  $I_F = 5 \text{ mA}$
- (4)  $I_F = 1 \text{ mA}$

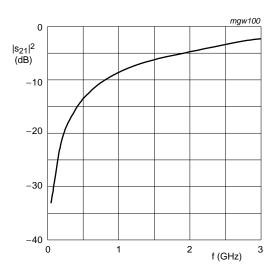
Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network. T $_{\rm amb}$  = 25  $^{\circ} C$ .

Fig 3. Insertion loss ( $|s_{21}|^2$ ) of the diode in on-state as a function of frequency; typical values



 $f = 1 \text{ MHz}; T_j = 25 ^{\circ}\text{C}$ 

Fig 2. Diode capacitance as a function of reverse voltage; typical values



Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit.  $\rm T_{amb}$  = 25  $^{\circ}\rm C.$ 

Fig 4. Isolation ( $|s_{21}|^2$ ) of the diode in off-state as a function of frequency; typical values

## 8. Package outline

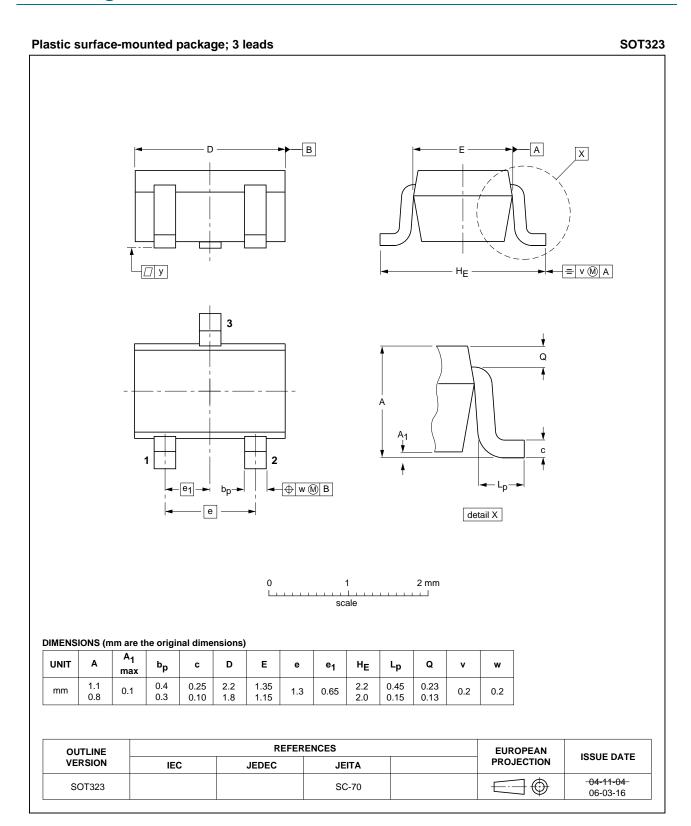


Fig 5. Package outline SOT323

## **Revision history**

#### Table 7. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP65-05W v.2	20100927	Product data sheet	-	BAP65-05W v.1
Modifications:		of this data sheet has been red FNXP Semiconductors.	esigned to comply w	ith the new identity
	<ul> <li>Legal texts h</li> </ul>	ave been updated.		
	• Figure 5: page	ckage outline drawing has bee	n updated to the late	est version.
	• Table 4 "Lim	<u>iting values"</u> : added T <sub>amb</sub> (amb	pient temperature).	
BAP65-05W v.1 (9397 750 08115)	20010507	Product specification	-	-

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#### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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